



20V P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

Product Summary

| BV _{DSS} | R _{DS(ON)} max | I _D max T _C = +25°C |
|-------------------|---|--|
| -20V | $5.5 \text{m}\Omega$ @ $V_{GS} = -4.5 \text{V}$ | -40A |
| | $7.5 \text{m}\Omega$ @ $V_{GS} = -2.5 \text{V}$ | -40A |

Description

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

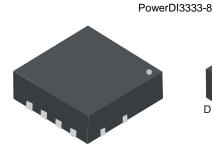
- Load Switch
- Power Management Functions

Features

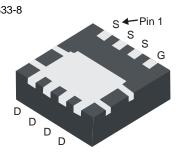
- Low R_{DS(ON)} ensures on state losses are minimized
- Small form factor, thermally efficient package enables higher density end products
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

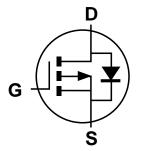
- Case: PowerDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe;
 Solderable per MIL-STD-202, Method 208 ⁽³⁾
- Weight: 0.030 grams (Approximate)







Bottom View



Equivalent Circuit

Ordering Information (Note 4)

| r. | | |
|---------------|---------------|-------------------|
| Part Number | Case | Packaging |
| DMP2006UFG-7 | PowerDI3333-8 | 2,000/Tape & Reel |
| DMP2006UFG-13 | PowerDI3333-8 | 3,000/Tape & Reel |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

PowerDI3333-8



S47 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 17 = 2017) WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | | |
|---|------------------|----------------|-----------------------|------|---|
| Drain-Source Voltage | V _{DSS} | -20 | V | | |
| Gate-Source Voltage | | | V_{GSS} | ±10 | V |
| Continuous Drain Current (Note 5) V_{GS} = -4.5V Steady State T_A = +25°C T_A = +70°C T_C = +25°C | | I _D | -17.5 -14.0 -40 | А | |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%) | I _{DM} | -80 | А | | |
| Maximum Continuous Body Diode Forward Current (Note 5) | | | Is | -2.2 | Α |
| Avalanche Current (Note 7) L = 0.1mH | | | I _{AS} | -23 | Α |
| Avalanche Energy (Note 7) L = 0.1mH | E _{AS} | 28 | mJ | | |

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | |
|---|----------------------|-----------------|------|------|
| Total Bower Dissinction (Note 5) | $T_A = +25^{\circ}C$ | ם | 2.3 | - W |
| Total Power Dissipation (Note 5) | $T_C = +25$ °C | P_{D} | 41 | |
| Thermal Resistance, Junction to Ambient | (Note 5) | D | 54 | |
| Thermal Resistance, Junction to Ambient | (Note 6) | $R_{\theta JA}$ | 136 | °C/W |
| Thermal Resistance, Junction to Case (Note 5) | R ₀ JC | 3.0 | | |
| Operating and Storage Temperature Range | $T_{J_i}T_{STG}$ | -55 to +150 | °C | |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

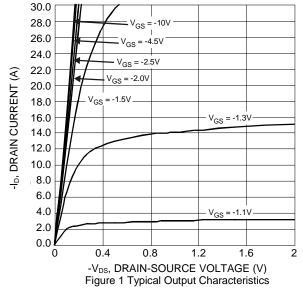
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|---|---------------------|------|------|------|-------|--|--|
| OFF CHARACTERISTICS (Note 8) | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | -20 | _ | _ | V | $V_{GS} = 0V, I_D = -250\mu A$ | |
| Zero Gate Voltage Drain Current | I _{DSS} | _ | _ | -1 | μΑ | $V_{DS} = -16V, V_{GS} = 0V$ | |
| Gate-Source Leakage | I _{GSS} | - | _ | ±100 | nA | $V_{GS} = \pm 8V$, $V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 8) | | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | -0.4 | _ | -1.0 | V | $V_{DS} = V_{GS}, I_{D} = -250 \mu A$ | |
| | | 1 | 4.2 | 5.5 | | $V_{GS} = -4.5V$, $I_{D} = -15A$ | |
| Static Drain-Source On-Resistance | D | 1 | 5.4 | 7.5 | mΩ | $V_{GS} = -2.5V, I_D = -10A$ | |
| Static Drain-Source On-Resistance | R _{DS(ON)} | _ | 8 | 12 | 11122 | $V_{GS} = -1.8V, I_{D} = -1A$ | |
| | | _ | 12 | 17 | | $V_{GS} = -1.5V, I_{D} = -1A$ | |
| Diode Forward Voltage | V_{SD} | _ | -0.7 | -1.2 | V | $V_{GS} = 0V, I_{S} = -10A$ | |
| DYNAMIC CHARACTERISTICS (Note 9) | | | | | | | |
| Input Capacitance | C _{iss} | _ | 5404 | 7500 | | V _{DS} = -10V, V _{GS} = 0V f = 1.0MHz | |
| Output Capacitance | Coss | _ | 728 | 1000 | pF | | |
| Reverse Transfer Capacitance | Crss | _ | 612 | 900 | | | |
| Gate Resistance | R_{G} | _ | 3.8 | 8 | Ω | $V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$ | |
| Total Gate Charge (V _{GS} = -4.5V) | Qg | _ | 64 | 100 | | | |
| Total Gate Charge (V _{GS} = -10V) | Qg | _ | 140 | 200 | nC | V 40V L 20A | |
| Gate-Source Charge | Q_{gs} | _ | 8.5 | 15 | nc nc | $V_{DD} = -10V, I_D = -20A$ | |
| Gate-Drain Charge | Q_{gd} | _ | 17 | 30 | | | |
| Turn-On Delay Time | t _{D(ON)} | _ | 9.1 | 20 | | | |
| Turn-On Rise Time | t _R | _ | 19 | 35 | | $V_{GS} = -4.5V, V_{DD} = -10V,$ | |
| Turn-Off Delay Time | t _{D(OFF)} | | 146 | 220 | ns | $R_G = 1\Omega$, $R_G = 1\Omega$, $I_D = -10A$ | |
| Turn-Off Fall Time | t _F | | 104 | 150 | | | |
| Reverse Recovery Time (Note 9) | t _{RR} | 1 | 61 | 100 | ns | I _F = -10A, di/dt = 100A/μs | |
| Reverse Recovery Charge (Note 9) | Q_{RR} | _ | 44 | 70 | nC | $I_F = -10A$, $di/dt = 100A/\mu s$ | |

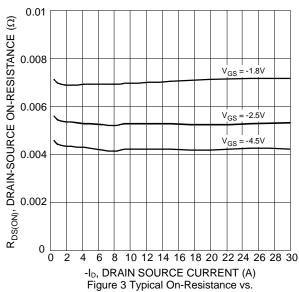
Notes:

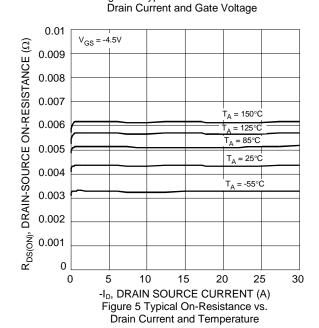
- 5. R_{BJA} is determined with the device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. R_{BJC} is guaranteed by design while R_{BJA} is determined by the user's board design.
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
- 7. UIS in production with L=0.1 mH, $T_J=+25 ^{\circ}C$.
- 8. Short duration pulse test used to minimize self-heating effect.
- 9. Guaranteed by design. Not subject to product testing.

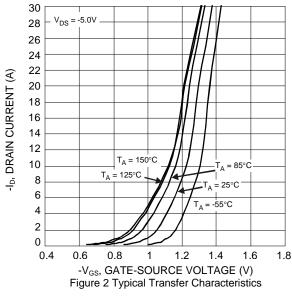


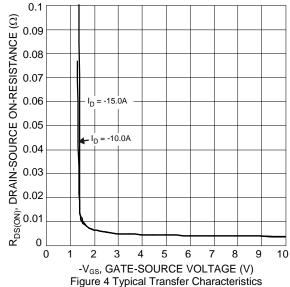












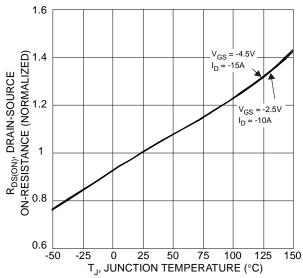
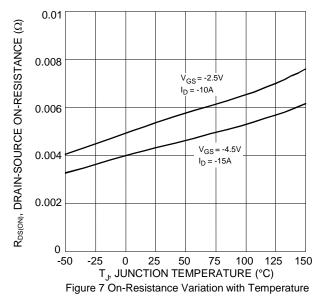
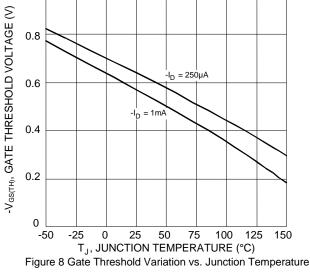


Figure 6 On-Resistance Variation with Temperature

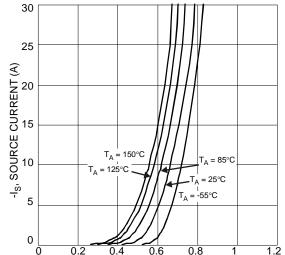






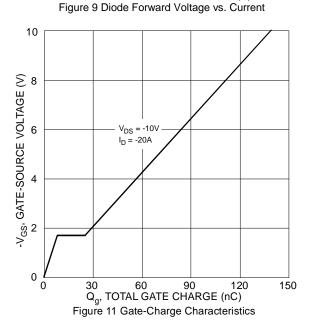


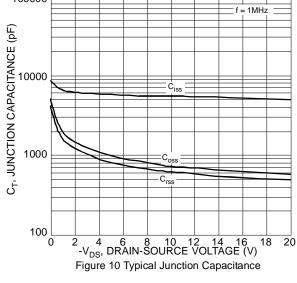
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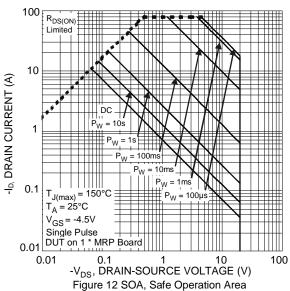


-V_{SD}, SOURCE-DRAIN VOLTAGE (V)











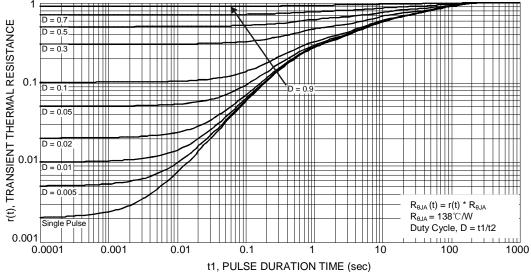


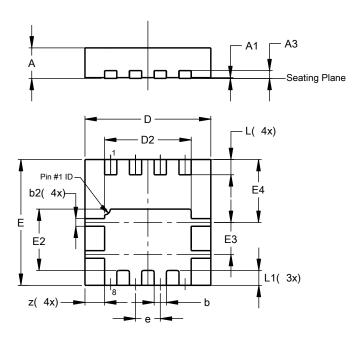
Figure 13 Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8

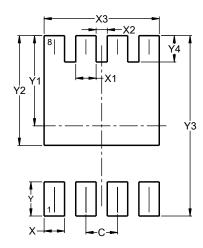


| PowerDI3333-8 | | | | | |
|----------------------|------|------|-------|--|--|
| Dim | Min | Max | Тур | | |
| Α | 0.75 | 0.85 | 0.80 | | |
| A1 | 0.00 | 0.05 | 0.02 | | |
| A3 | _ | _ | 0.203 | | |
| b | 0.27 | 0.37 | 0.32 | | |
| b2 | 0.15 | 0.25 | 0.20 | | |
| D | 3.25 | 3.35 | 3.30 | | |
| D2 | 2.22 | 2.32 | 2.27 | | |
| Е | 3.25 | 3.35 | 3.30 | | |
| E2 | 1.56 | 1.66 | 1.61 | | |
| E3 | 0.79 | 0.89 | 0.84 | | |
| E4 | 1.60 | 1.70 | 1.65 | | |
| е | - | _ | 0.65 | | |
| L | 0.35 | 0.45 | 0.40 | | |
| L1 | _ | _ | 0.39 | | |
| Z | _ | _ | 0.515 | | |
| All Dimensions in mm | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8



| Dimensions | Value (in mm) |
|------------|---------------|
| C | 0.650 |
| X | 0.420 |
| X1 | 0.420 |
| X2 | 0.230 |
| Х3 | 2.370 |
| Y | 0.700 |
| Y1 | 1.850 |
| Y2 | 2.250 |
| Y3 | 3.700 |
| Y4 | 0.540 |

March 2017

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